NSN 5962-01-385-8971

Memory Microcircuit - Page 1 of 1

Fiig: A458a0



View Online at https://aerobasegroup.com/nsn/5962-01-385-8971
Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Bipolar and electrostatic sensitive and monolithic and programmed
Inclosure Configuration:
Dual-in-line Dual-in-line
Case Outline Source And Designator:
D-8 mil-m-38510
Product Name:
16-input 8-output and-or invert gate array
Voltage Rating And Type Per Characteristic:
-0.5 volts absolute input and 5.5 volts absolute input
Memory Device Type:
Pal
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-883
standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 printed circuit
Departure From Cited Designator:
Programmed per: 7358066-00
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Vos - demil/mli